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## Reducing hot carrier cooling rate in metal halide perovskites through lead vacancies: time-domain *ab initio* analysis<sup>†</sup>

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Hybrid organic–inorganic perovskites are promising for optoelectronic applications, yet the impact of intrinsic defects on hot carrier dynamics remains poorly understood. Here, we investigate hot carrier dynamics in methylammonium lead triiodide (MAPbI<sub>3</sub>) perovskite containing Pb vacancies, a prevalent defect type, using *ab initio* nonadiabatic molecular dynamics. We observe pronounced slower hot carrier cooling in Pb vacancy-containing MAPbI<sub>3</sub> compared to pristine system. In particular, the hot hole cooling in the Pb vacancy system is approximately an order of magnitude slower than that of pristine perovskite for states situated ~0.5 eV below the top of the valence bands. This deceleration arises primarily from reduced nonadiabatic couplings due to charge state localization and suppressed fluctuations of the inorganic sub-lattice, facilitated by the enhanced rotational disorder of MA cations in the presence of Pb vacancies. Additionally, Pb vacancies introduce intraband defect states capable of trapping photogenerated hot holes, further delaying the hot carrier cooling process. The absence of trap-assisted hot carrier cooling dynamics in hybrid perovskite is consistent with the well-established consensus of defect tolerance in these materials. Our findings provide crucial insights into defect-mediated hot carrier dynamics in hybrid perovskites, holding significant implications for advancing the development of perovskite solar cells and related devices through defect engineering.

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### 1. Introduction

Metal halide perovskites (MHPs) have attracted considerable attention as emerging semiconductor materials in recent years, particularly for next-generation solar cells, owing to their remarkable performance.<sup>1–4</sup> The reported power conversion efficiency (PCE) for perovskite solar cells (PSCs) has rapidly evolved from 3.8%<sup>5</sup> to 25.8%<sup>6</sup> within just a few years. This advance is attributed to their distinctive photophysical properties. However, further improvements in PSC efficiency

are impeded by various energy loss channels for the photo-excited carriers. To address this challenge, an unconventional strategy is to slow down the relaxation process of carriers with excess energy, known as hot carriers (HCs), generated by above-bandgap excitation. HCs relax to band extrema by dissipating their excess energy to the lattice *via* charge-phonon scattering. Rapid HC cooling severely undermines the extraction and utilization of photogenerated carrier energy.<sup>7</sup> Therefore, reducing the carrier thermalization rate is crucial for achieving higher performance in optoelectronic applications relying on HCs, such as hot carrier solar cells, *etc.*

Extensive research efforts have been dedicated to understanding the mechanisms and dynamics of HC cooling in MHPs.<sup>8–12</sup> Early studies revealed that carrier thermalization in MHPs occurs on an ultrafast timescale (within hundreds of femtoseconds), making HC extraction extremely challenging.<sup>13</sup> Recent findings have shown that MHPs exhibit slow HC cooling dynamics, which is linked to various photophysical mechanisms such as hot phonon bottleneck, Auger heating, polaron formation, and band filling effect.<sup>14–17</sup> These findings have initiated hot discussions about the potential of PSCs utilizing hot carriers. Several studies have regulated HC cooling rates through doping or chemical engineering to facilitate

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<sup>†</sup>Electronic supplementary information (ESI) available: Band structures and projected density of states. The crystal orbital Hamilton population analysis. Root-mean-square displacement velocities for each atomic species. The calculated Pb–I bond lengths and Pb–I–Pb bond angles. Charge density distributions for valence band and conduction bands state. Population decay plots for each excited state. See DOI: <https://doi.org/10.1039/d4qi00833b>

efficient HC extraction and utilization. It was reported that HC relaxation in MHPs can be slowed down by inclusion of dipolar A-site cations,<sup>18–21</sup> mixing halogen atoms,<sup>22,23</sup> alloying divalent metal ions (e.g.,  $Zn^{2+}$  or  $Sn^{2+}$ ),<sup>24–28</sup> incorporation of alkali cations,<sup>29</sup> surface passivation treatments,<sup>30,31</sup> manipulations of dielectric confinement, and Rashba band splitting.<sup>32</sup> Furthermore, other works have explored the size, dimensionality, and shape dependence of HC cooling dynamics using first-principles calculations.<sup>33</sup> However, less attention has been given to controlling HC cooling *via* defect engineering. Existing literature on this topic is scarce, with a focus mainly on halide interstitial and vacancy defects.<sup>34,35</sup> Notably,  $Pb_v$  vacancies ( $Pb_v$ ) are prevalent defects observed in perovskite materials due to their low formation energy under  $Pb$ -poor/I-rich chemical conditions. The presence of  $Pb_v$  in  $MAPbI_3$  based perovskites has been experimentally identified using positron annihilation lifetime spectroscopy.<sup>36,37</sup> Previous studies have indicated that  $Pb_v$  can change localization of photoexcited electron and hole states, thereby suppressing radiative and nonradiative electron–hole recombination processes in MHPs.<sup>38,39–41</sup> Understanding the extent to which HC cooling dynamics can be manipulated by  $Pb_v$  is urgently needed, underscoring the importance of further in-depth theoretical investigations.

In this work, using *ab initio* NA–MD simulations, we investigated in detail the HC cooling dynamics of  $MAPbI_3$  perovskites with and without  $Pb_v$ . Our results demonstrate that  $Pb_v$  induces a slowdown in HC cooling dynamics. The presence of  $Pb_v$  disrupts the structural symmetry and localize charge density distributions, resulting in reduced overlap between states within valence band (VB) and conduction band (CB). The decreased thermal motion of inorganic atoms, facilitated by  $Pb_v$ , decreases fluctuations of excited state energies, leading to weaker electron-vibrational interaction. Reduced wavefunction overlaps and smaller nuclear displacements contribute the weakened nonadiabatic (NA) couplings, consequently reducing the HC cooling rate. Additionally, without creating mid-gap defect states,  $Pb_v$  introduces intraband defect levels inside VB. These defect states are capable of trapping holes with the trapped holes staying longer at defect sites, impeding the relaxation of hot holes towards the band edge. Furthermore, hot electron and hole relaxations are facilitated exclusively by low-frequency modes. The synergistic effects of these aspects lead to a 10-fold decrease in the hole relaxation rate in the presence of  $Pb_v$  under moderate excitation energy, whereas the change in the electron relaxation rate is less pronounced. These results highlight the beneficial role of  $Pb_v$  in HC cooling dynamics, which is important for further development of PSCs.

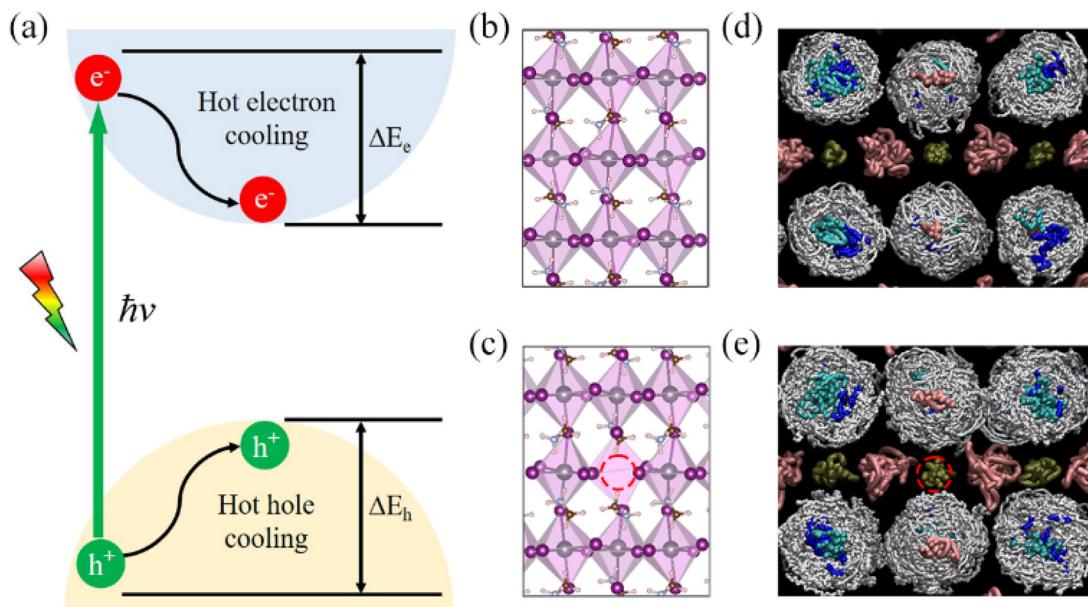
## 2. Computational methodology

Geometry optimization, static electronic structure calculation, and adiabatic molecular dynamics (MD) simulations were carried out with the VASP code.<sup>42,43</sup> The exchange–correlation

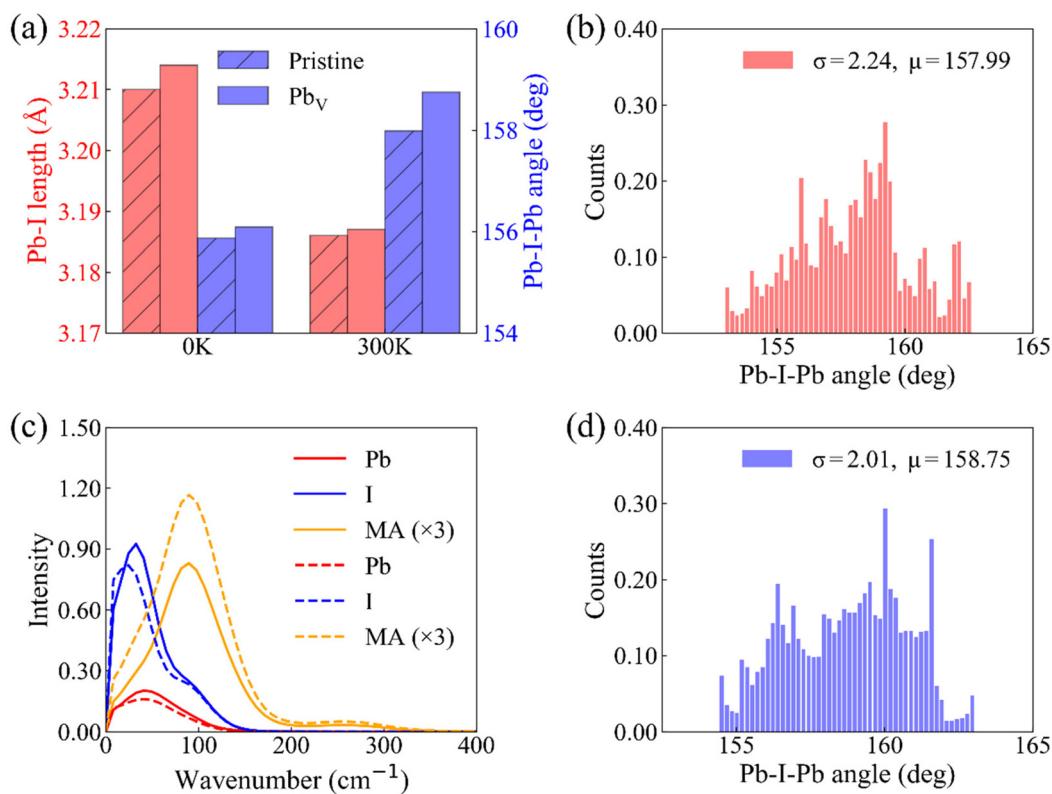
interaction was described using the Perdew–Burke–Ernzerhof (PBE) functional in the generalized gradient approximation (GGA) with a plane-wave basis set. The plane-wave energy cutoff was set to 400 eV. For geometry optimization,  $\Gamma$ -centered  $2 \times 2 \times 1$  Monkhorst–Pack  $k$ -point mesh was employed, while the electronic properties were calculated with a denser  $4 \times 4 \times 2$   $k$ -point mesh for more accurate results. During the geometry optimization, all atoms were allowed to move while maintaining the fixed lattice vectors. The optimization was deemed finished when all ion forces were smaller than  $0.01$  eV  $\text{\AA}^{-1}$ . The energy convergence criterion for the self-consistency cycle of solving the Kohn–Sham equations was set to  $10^{-4}$  eV. Dispersion interactions were account for using the DFT-D3 scheme proposed by Grimme *et al.*<sup>44</sup> Subsequently, the systems were heated to 300 K using repeated velocity rescaling, followed by a 5 ps MD production run in the microcanonical ensemble (NVE) with a time step of 1 fs. The electronic properties of the MD configurations were re-computed for each MD configuration to obtain the time-dependent adiabatic energies and NA couplings, forming vibronic Hamiltonian matrices. These time-dependent data were further utilized for NA–MD simulations employing the fewest switches surface hopping (FSSH) algorithm under the classical path approximation, implemented in the PYXAID code.<sup>45,46</sup> 50 geometries were randomly sampled from the adiabatic MD trajectories and used as initial conditions in the NA–MD calculations. The results were averaged over 1000 stochastic realizations of the surface hopping simulation to achieve convergence. A detailed description of NA–MD methodology can be found elsewhere.<sup>45,46</sup> The method has been widely used to model carrier trapping, relaxation, and recombination in various nanoscale systems.<sup>22,47–59</sup>

## 3. Results and discussion

Fig. 1a illustrates the fundamental photophysical processes governing HC cooling dynamics in semiconductors. To model HC cooling dynamics, we constructed a large supercell based on a  $2 \times 2 \times 2$  expansion of the tetragonal  $MAPbI_3$  unit cell with experimental lattice constants, containing 384 atoms in total. The  $Pb_v$  defect is created by removing a  $Pb$  atom from the pristine supercell structure. Fig. 1b and c present the optimized structures of  $MAPbI_3$  perovskites with and without  $Pb_v$ , respectively. It is clear that the pristine system shows large octahedral distortion from the ideal perovskite structure, a well-known characteristic feature for the tetragonal  $MAPbI_3$  perovskite. The presence of  $Pb_v$  decreases this distortion, leading to a reduction in the tilting of the  $[PbI_6]^{4-}$  octahedron. This structural adjustment is accompanied by an elongation of the  $Pb$ –I bonds and an increase in the  $Pb$ –I–Pb bond angles, as summarized in Fig. 2a and Table S1.<sup>†</sup> We observe the same phenomenon for the structures averaged over 5 ps MD trajectories. The structural reorganization induced by  $Pb_v$  results in internal strain relaxation, leading to a more ordered arrangement of inorganic sub-lattice to accommodate the additional



**Fig. 1** Schematic illustration of hot carrier relaxation (a). Optimized ground state structures of pristine MAPbI<sub>3</sub> (b) and MAPbI<sub>3</sub> with Pb<sub>V</sub> (c). Superimposed snapshots of local structures from 5 ps molecular dynamics trajectories of pristine (d) and defective (e) MAPbI<sub>3</sub>. The red dashed circle denotes the location of vacancy site. The motion of MA cations in the defective system is enhanced due to the additional space created by Pb vacancies.



**Fig. 2** The Pb–I bond lengths and Pb–I–Pb bond angles of static structures at 0 K and average values from MD trajectories at 300 K (a). The statistical distributions of the Pb–I–Pb bond angles obtained from MD trajectories in pristine (b) and defective (d) systems. The vibrational density of states obtained by Fourier transform of the velocity autocorrelation function from MD trajectories for pristine (solid line) and defective (dotted line) MAPbI<sub>3</sub> perovskites (c). Only the low-frequency modes in the range of 0–400 cm<sup>-1</sup> are shown. The defective system exhibits larger Pb–I–Pb angle, for both static and MD structure, and smaller standard deviation, evidencing the suppressed fluctuations of the inorganic lattice in the presence of Pb vacancies.

space created by the vacancies. The internal strain relaxation *via* vacancy defect formation has been also reported in oxide perovskites.<sup>60,61</sup> During MD simulation, all atoms exhibit fluctuations around their equilibrium positions, confirming thermal stability of both structures. MA cations display more pronounced fluctuations compared to the inorganic lattice, attributed to their lighter mass relative to Pb and I atoms. Notably, the MA fluctuation is enhanced in the defective system, Fig. 1d and e. This rotational motion of MA cations influences the dynamical behavior of the inorganic sub-lattice, modulating the optoelectronic properties of the  $\text{MAPbI}_3$  perovskite.

In order to understand how  $\text{Pb}_v$  influences the lattice dynamics, we computed the root-mean-square (RMS) displacement of each atomic species, as listed in Table S2.<sup>†</sup> The RMS data indicate that Pb vacancies slightly enhance the motion of MA cations while suppressing the vibrations of Pb and I atoms. This phenomenon likely stems from the enhanced rotational disorder of MA cations facilitated by the additional spatial freedom afforded by  $\text{Pb}_v$ . In turn, this imposes steric hindrance, constraining fluctuations of the inorganic sub-lattice. The observation is further supported by the statistical analysis of the Pb–I–Pb angles, Fig. 2b and d. We extend our analysis to the vibrational density of states (VDOS) obtained by Fourier transforming the velocity autocorrelation function from a 5 ps MD trajectory at 300 K, Fig. 2c. The VDOS is projected onto individual species of interests including Pb, I, and organic cation. Such an analysis has been widely used to reveal the structure and dynamic behavior of a system, especially hybrid perovskites.<sup>62–64</sup> We focus exclusively on the low-frequency modes in the range of 0–400  $\text{cm}^{-1}$ , predominately associated with vibrations of the inorganic components, albeit with a significant contribution from organic cation motion. Our results reveal that while the intensity of vibrational modes associated with the Pb and I components exhibits a slight decrease, those involving MA cations demonstrate a notable increase in the Pb vacancy system compared to the pristine system. This finding further supports the argument that the dynamical fluctuation of the inorganic sub-lattice is restricted by the rotational disorder of the organic cations. Moreover, the enhanced rotational disorder of the organic cations in the presence of  $\text{Pb}_v$  may decrease the possible formation of hydrogen bonding, thereby further reducing the octahedral tilting. It is noteworthy that the “locking” effect of the MA cations on the inorganic sub-lattice has previously been reported in the context of temperature effects in hybrid perovskites.<sup>3,65</sup> The above analysis reveals the intricate interplay between structural dynamics and defect-induced perturbation in hybrid perovskites.

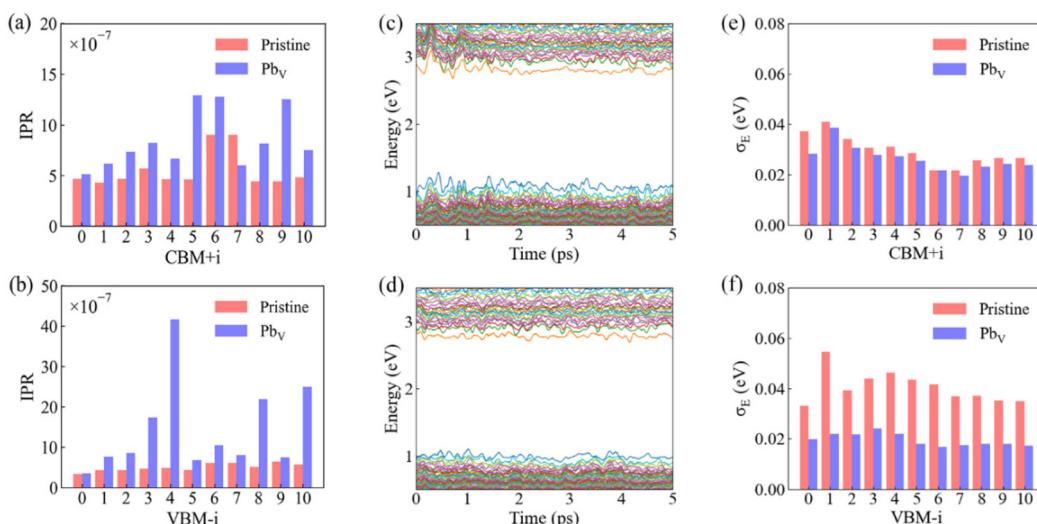
Band structures and projected density of states (pDOS) for pristine and Pb-vacancy-containing systems are shown in Fig. S1a and b.<sup>†</sup> The band structures illustrate that the direct band gap between the VB maximum (VBM) and CB minimum (CBM) at the G-point for pristine  $\text{MAPbI}_3$  is approximately 1.62 eV, consistent with experiment.<sup>66</sup> Analysis of the pDOS suggests that the VB is predominantly composed of I-5p states

with a minor contribution from Pb-6s states, while the CB is primarily comprised of Pb-6p states. The relaxation of hot holes and electrons mainly involves the vibrational motion of Pb and I atoms, respectively, driving charge-phonon interactions. The Crystal Orbital Hamilton Population (COHP) analysis, presented in Fig. S2,<sup>†</sup> further suggests that the VBM is dominated by the anti-bonding hybridization of Pb-6s/I-5p states, whereas the CBM consists of non-bonding Pb-6p orbitals with negligible coupling to I-5p. Consequently, VB levels are more sensitive to changes in the inorganic framework, including variations in the Pb–I–Pb bond angle and Pb–I bond length. Although MA cations do not directly contribute to states near the band edges, they indirectly influence HC dynamics through electrostatic and steric interactions with the inorganic Pb–I lattice. The analysis of pDOS reveals an asymmetric distribution, with the pDOS of VB higher than CB, indicating a denser distribution of states in the former. While a denser DOS in the VB typically accelerates hole relaxation relative to electrons, this may not always hold true, particularly in the presence of defects, as we shall discuss below.  $\text{Pb}_v$  slightly increases the band gap by approximately 0.06 eV without introducing mid-gap states. The removal of Pb atoms disrupts Pb–I bonds, creating defect states originating from the dangling bonds of surrounding I atoms. These defect levels, located between the VBM and the I-5p atomic orbital level, as illustrated by the diagram for the interaction between Pb and I atomic orbitals in Fig. S1c,<sup>†</sup> form intra-band defect states characterized by flat energy dispersion profiles, indicative of localized trap states.

To quantify the orbital localization, we calculated the inverse participation ratio (IPR) of Kohn–Sham states based on the optimized ground state structures for both systems. The IPR is defined as:

$$\text{IPR} = N \times \frac{\sum \psi_i^4}{(\sum \psi_i^2)^2}$$

where  $N$  represents the number of grid points, as determined by the kinetic energy cutoff for the plane-wave basis.  $\psi_i$  denotes the amplitude of the normalized wavefunction for a given Kohn–Sham state at grid  $i$ . An IPR value characterizes the inverse spatial extent for a state, ranging from 1 for perfect localization to 0 for full delocalization. Larger IPR values indicate more localized electronic states. In Fig. 3a and b, we present IPR values of CBM +  $i$  and VBM- $i$  (where  $i = 0–10$ ) for both systems. We observe that the IPR values found are generally larger for VB than CB states, implying stronger charge localization in the former. This can be attributed to the dominance of Pb-s/I-p states in the VB and Pb-p states in the CB. Pb vacancies further enhance charge localization, particularly in the VB, as evidenced by the comparison of VBM-4 and CBM + 5 orbitals for both systems, Tables S3–S6.<sup>†</sup> The removal of two electrons by Pb vacancies results in electron-deficient I atoms surrounding the vacancy sites, leading to the attraction (repulsion) of electrons (holes) and induction of spatially localized charge density distributions. Moreover, Pb vacancies introduce



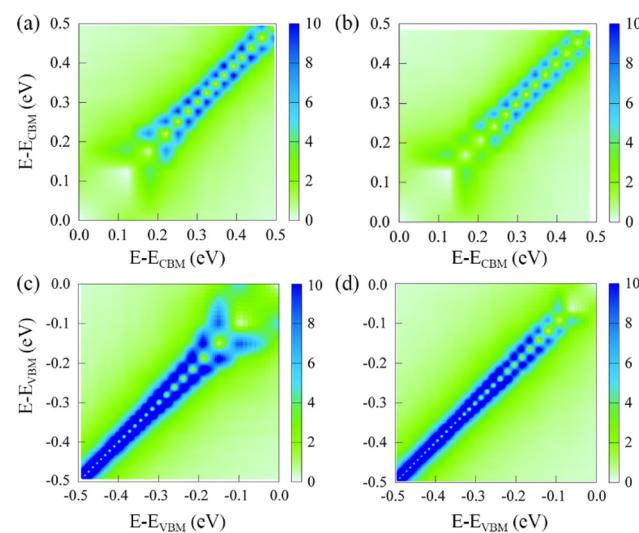
**Fig. 3** The inverse participation ratio (IPR) of CB (a) and VB (b) orbitals for pristine and defective  $\text{MAPbI}_3$  based on the optimized ground state structures. Time evolution of VB and CB energy levels in pristine (c) and defective (d)  $\text{MAPbI}_3$ . The standard deviation ( $\sigma_E$ ) of the energy level fluctuations for CB (e) and VB (f). The  $\text{Pb}_\text{V}$  system shows larger IPR values for VB because it introduces trap states within VB and destroys the structural symmetry, resulting in more localized charge density distributions. Generally, the energy levels of the defective system, in particular the VB states, show smaller fluctuations compared to the pristine system due to the weaker motions of inorganic Pb and I atoms.

localized intra-band defect states in the VB, further contributing to charge localization. The charge localization inferred from the IPR analysis is consistent with the orbital distribution presented in Tables S3–S6.† The increased charge localization reduces wavefunction overlap, resulting in smaller NA electron–phonon couplings.

We proceed to analyze the time evolution of Kohn–Sham orbital energies and the standard deviations of these energies, as shown in Fig. 3c and d. Vibrations of lattice atoms modulates the electronic energy levels, creates electron–phonon coupling, and drives transitions between electronic states. The inherent softness of the perovskite lattice results in substantial fluctuations in VB and CB levels, reaching magnitudes comparable to or several times that of  $k_\text{B}T$  ( $\sim 0.026$  eV). The presence of  $\text{Pb}_\text{V}$  reduces the fluctuations of the VB and CB levels, as indicated by the smaller standard deviation data calculated for each orbital, Fig. 3e and f. This reduction stems from the decreased amplitude of Pb and I motion induced by  $\text{Pb}_\text{V}$ . NA electron–phonon coupling reflects wavefunction sensitivity to nuclear motion, and can be related to the second derivative of the energy levels along an MD trajectory. Consequently, the degree of fluctuations in orbital levels serves as an indicator of the relative strength of NA couplings. It is anticipated that  $\text{Pb}_\text{V}$  should decrease NA coupling compared to the pristine system. The calculated standard deviations for VB levels generally surpass those for CB levels, indicating stronger electron–phonon couplings for states in the VB than the CB. This disparity arises because VB states are formed by an anti-bonding hybridization of Pb-s/I-p atomic orbitals, making them more sensitive to structural changes of the inorganic sub-lattice.

Nonadiabatic couplings play a critical role in influencing the HC cooling process. According to the definition of the NA

coupling, it is related to wavefunction overlap, nuclear velocity, and energy difference between initial and final states. Here we have calculated the average absolute values of the NA couplings between states in VB or CB. Fig. 4 presents 2D maps of the NA coupling for the pristine and defective systems. The sub-diagonal matrix elements represent the NA coupling



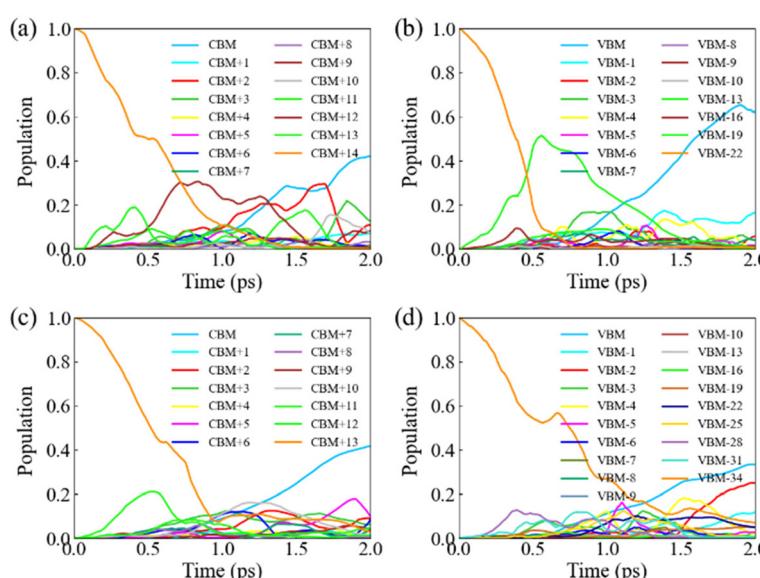
**Fig. 4** The averaged absolute nonadiabatic couplings (NACs) between states for CB (a and b) and VB (c and d) in pristine (a and c) and defective (b and d)  $\text{MAPbI}_3$ . VB states couple more strongly than CB states because the VB is denser than the CB.  $\text{Pb}_\text{V}$  generally decreases the NAC magnitude compared to the pristine system because of the suppressed motion of inorganic atoms and the localized trap states introduced by the defect.

between adjacent states. Strong coupling values along the sub-diagonal lines indicate an enhanced tendency for non-radiative transitions between nearby states with similar energies. Conversely, NA couplings between states separated by large energy gaps yield smaller values, consistent with the expected inverse relationship between coupling strength and energy gap. However, direct NA transitions between low energy and high energy states within VB or CB remain possible due to non-zero coupling values away from the sub-diagonal lines. Notably, NA couplings between VB states generally exceed those between CB states. This difference can be attributed to the larger density of states in the VB, resulting in denser electronic states and smaller energy spacings. Importantly, we observe that  $\text{Pb}_\text{v}$  leads to a reduction in NA couplings between states within both VB and CB compared to pristine  $\text{MAPbI}_3$ . This reduction in the NA coupling strength can be attributed to decreased nuclear velocities associated with weaker fluctuations of the Pb-I framework and smaller overlap of Kohn-Sham orbitals stemming from the localized charge density distributions. The observed differences in the NA couplings are expected to modulate HC relaxation dynamics, underscoring the significance of defect-induced structural perturbations.

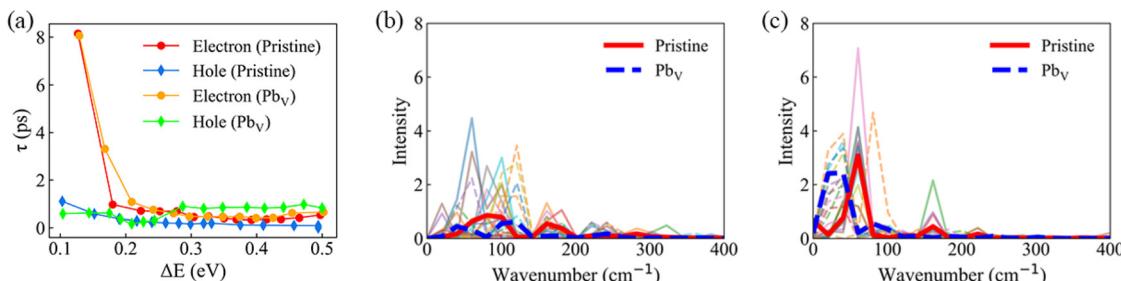
Next, we discuss HC cooling dynamics for pristine and defective systems. We use NA-MD simulation in the single-particle description and ignore the electron-hole Coulomb interaction given the small exciton binding energy in these perovskite materials. The approximation allows for a separate treatment of the hot electron and hot hole relaxation processes. The population decay for each excited state is presented in Tables S7–S10.† To facilitate comparison, Fig. 5 illustrates the time-dependent excited state population following initial excitation to states with excess energy  $\Delta E \approx 0.5$  eV relative to band edges. The lifetimes ( $\tau$ ) are obtained by fitting the population

decays using an exponential function,  $\exp(-t/\tau)$ . First of all, we find that hot carrier cooling primarily occurs through state-to-state transitions, as evidenced by the considerable population of intermediate states. We emphasize that the HC cooling can also include other relaxation channels due to non-negligible coupling values between states separated by large energy gaps. In pristine  $\text{MAPbI}_3$ , HC relaxation occurs on a timescale of 89 fs and 572 fs for holes and electrons, respectively, which are in agreement with the timescales measured by experimental transient absorption spectroscopy.<sup>13</sup> The faster hole relaxation relative to electron relaxation can be attributed to the stronger NA coupling between states within the VB, arising from the higher DOS and smaller energy spacings. This is consistent with the previous work by Kawai *et al.* who demonstrated that large DOS facilitates rapid carrier cooling using many body perturbation theory calculations.<sup>67</sup> Interestingly,  $\text{Pb}$  vacancies substantially extend the lifetime of hot hole cooling (820 fs), while showing only a slight increase for hot electron cooling (645 fs) compared to the pristine system. The slower hot hole cooling with respect to the hot electron cooling in defective perovskite is in contrast to the trend observed in pristine perovskite. This is because  $\text{Pb}_\text{v}$  introduces intra-band defect states that are capable of trapping holes within the VB, slowing down hole relaxation towards the band edge, though NA couplings between states in both VB and CB are reduced in the presence of  $\text{Pb}$  vacancies. Longer carrier cooling time is important for efficient HC harvesting.

We further studied the HC cooling dynamics as a function of excess energy for the considered systems, Fig. 6a. Overall, all cooling processes happen within a time scale of few picoseconds. Our results show a clear dependence of the HC cooling time on excess energy for the studied systems. From Fig. 6a, hot electron relaxation is more sensitive to the excess



**Fig. 5** Time evolution of excited state populations of electrons and holes during the cooling processes for pristine (a and b) and defective (c and d)  $\text{MAPbI}_3$  starting with  $\Delta E \approx 0.5$  eV excess energy relative to the band edges.



**Fig. 6** Lifetime ( $\tau$ ) of hot carriers as a function of excess energy relative to the band edge (a). Holes relax faster than electrons because of stronger nonadiabatic couplings. Pb vacancy introduces defect states within the VB that are capable of trapping holes, slowing down the hole relaxation process. The spectral densities of CB (b) and VB (c) states with excess energy  $\Delta E \leq 0.5$  eV for the pristine and  $\text{Pb}_V$  systems, obtained by Fourier transform of time-dependent orbital energies. The bold line represents the averaged spectrum for pristine (solid line) and defective (dash line) systems. Holes show higher peak intensity because of the stronger fluctuation of orbital energies, arising from the anti-bonding nature of VB states, making them more sensitive to atomic motions.

energy than hot hole relaxation. Particularly, for pristine  $\text{MAPbI}_3$ , higher excitation energy leads to faster electron relaxation, consistent with report of a hot-phonon bottleneck observed at low excitation pump fluences.<sup>68</sup> The observation can be explained by the significantly denser states in the CB in higher energy regions, providing more relaxation channels for HCs, Fig. 3c and d. The electron relaxation dynamics exhibit a similar excitation energy dependence in the defective system as in the pristine system. However, hot hole relaxation displays longer relaxation times with increasing excitation energy, especially for excess energies exceeding  $\sim 0.28$  eV. The hot hole cooling rates are relatively similar between the pristine and defective systems when the excess energy is less than  $\sim 0.28$  eV. This behavior can be attributed to the presence of intra-band trap states and to the reduced NA couplings in the VB. The absence of accelerated trap-assisted HC cooling is also in agreement with the experimental observation.<sup>69</sup> The NA-MD results offer valuable insights into HC dynamics at varying excitation energies with and without the presence of Pb vacancies.

In order to examine the phonon modes driving the HC cooling process, in Fig. 6b and c we present the power spectra obtained by performing Fourier transform of autocorrelation functions of time-dependent orbital energies. The heights of the peaks of the power spectra characterize the strengths of electron-phonon coupling for the given phonon modes. Our analysis reveals that the power spectra for both electron and hole relaxations are predominantly influenced by low-frequency modes in the range of  $0\text{--}200\text{ cm}^{-1}$ , with minor contributions from high-frequency modes between  $200\text{--}400\text{ cm}^{-1}$ . Notably, holes exhibit more pronounced coupling to modes in the  $0\text{--}100\text{ cm}^{-1}$  range compared to electrons, indicating a stronger charge-phonon interaction during hole relaxation. The phonon modes below  $100\text{ cm}^{-1}$  are primarily attributed to Pb-I stretching and bending, as identified through Raman spectroscopy.<sup>70</sup> These modes determine NA couplings because they originate from the inorganic sub-lattice that supports charge carriers. The modes for frequencies larger than  $130\text{ cm}^{-1}$  arise mainly from vibrational motions of the organic

cations. In particular, the signals around  $200\text{ cm}^{-1}$  are due to the torsional mode of the MA cation.<sup>70,71</sup> Furthermore, the introduction of  $\text{Pb}_V$  induces a red-shift and suppression of low-frequency phonon modes for both electron and hole relaxations. This phenomenon aligns intuitively with our analysis of the stiffness of the inorganic network. The above results highlight the importance of Pb vacancies in tuning the vibrational characteristics and, correspondingly, the electron-phonon interactions responsible for HC cooling.

The exceptional performance of the  $\text{MAPbI}_3$  perovskite can be attributed to defect-tolerance, that is, shallow-level defects have low formation energies, while deep-level defects are hard to form. Deep-level defects serve as nonradiative electron-hole recombination centers, significantly deteriorating the performance of solar cells. In contrast, shallow level defects are generally considered benign. Through our investigations, we have revealed that Pb vacancies do not generate mid-gap states, rather, they contribute to enhancing the PSCs performance by delaying the cooling dynamics of hot carriers. We propose that shallow-level defects play a crucial role in decreasing the HC cooling rate by localizing charge density within VB or CB, decreasing wavefunction overlap, reducing the electronic density of states near the band edges, and stiffening the lattice dynamics. This explanation is supported by experimental observations demonstrating the absence of accelerated trap-assisted hot carrier cooling in hybrid perovskites.<sup>69</sup> The favorable defect properties in hybrid perovskites stem not only from the high formation energies of deep-level defects but also from the beneficial behavior of shallow defects in HC cooling dynamics. While our study focuses on  $\text{Pb}_V$  in MHPs, the insights gained from our work are applicable to other common defects, such as halide interstitials. Recent works indicate that negatively charged iodine interstitial defects introduce localized intra-band states within CB, disrupting band degeneracy, decreasing nonadiabatic couplings, and subsequently slowing down hot electron cooling,<sup>34</sup> which is in qualitative agreement with the analyses presented in this work. These findings contribute to a deeper understanding of the well-established defect-tolerance reported for hybrid per-

ovskites, thereby advancing their potential for various optoelectronic applications.

## 4. Conclusions

In summary, we have elucidated the influence of  $\text{Pb}_\text{V}$  on the dynamics of hot carriers in the  $\text{MAPbI}_3$  perovskite using *ab initio* NA-MD simulations. The detailed mechanism and timescale of hot carrier dynamics are established in this work. Our findings reveal that  $\text{Pb}_\text{V}$  induce internal strain relaxation and structural reorganization, leading to elongation of Pb–I bond lengths and alteration of Pb–I–Pb bond angles. This renders the VB more susceptible to thermally induced structural changes. Additionally, Pb vacancies promote rotational disorder of MA cations, constraining the dynamic fluctuations of the inorganic sub-lattice that supports charge carriers. Consequently, both VB and CB exhibit weaker fluctuations in energy levels. Pb vacancies reduce the nonadiabatic couplings because of the charge state localization resulting from structural perturbations and the reduced nuclear velocity. For pristine perovskite, hot electrons and holes with an excess energy of approximately 0.5 eV relax within a sub-ps timescale, consistent with recent experimental observations. Notably, hole relaxation occurs at a faster rate than electron relaxation in the pristine system.  $\text{Pb}_\text{V}$  slows down the hot carrier cooling process, particularly affecting hot holes, which can be attributed to the reduced nonadiabatic coupling and the trapping of hot holes by intraband defect states introduced by  $\text{Pb}_\text{V}$ . Furthermore, Pb vacancies lead to weaker electron-vibrational interaction due to the suppressed motion of Pb and I atoms. Importantly, the absence of trap-assisted hot carrier cooling dynamics observed in our study aligns with ultrafast spectroscopy experiments on MHPs and supports the widely accepted notion of defect tolerance in these materials. Our theoretical insights provide a comprehensive understanding of the commonly present Pb vacancies and their role in the fundamental mechanisms governing hot carrier dynamics of halide perovskites. This knowledge can aid in the design of high-efficiency PSCs and related devices through targeted defect engineering strategies.

## Conflicts of interest

There are no conflicts to declare.

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